October 1999 Revised October 1999 74LCX06 Low Voltage Hex Inverter/Buffer with Open Drain Outputs

# 74LCX06 Low Voltage Hex Inverter/Buffer with Open Drain Outputs

#### **General Description**

FAIRCHILD

SEMICONDUCTOR

The LCX06 contains six inverters/buffers. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The outputs of the LCX06 are open drain and can be connected to other open drain outputs to implement active LOW wire AND or active HIGH wire OR functions.

The 74LCX06 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

# Features

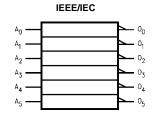
- 5V tolerant inputs
  2.3V–3.6V V<sub>CC</sub> specifications provided
- 3.7 ns  $t_{PD}$  max (V<sub>CC</sub> = 3.3V), 10 µA I<sub>CC</sub> max
- Power down high impedance inputs and outputs
- ±24 mA output drive ( $V_{CC} = 3.0V$ )
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- Functionally compatible with 74 series 05
- ESD performance:
  - Human body model > 2000V Machine model > 200V

# **Ordering Code:**

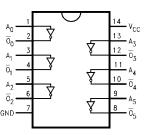
Order Number	Package Number	Package Description
74LCX06M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX06SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX06MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

#### Logic Symbol



#### **Connection Diagram**



#### **Pin Descriptions**

Pin Names	Description
A <sub>n</sub>	Inputs
Ōn	Outputs

74LCX06

### Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V <sub>CC</sub>	Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to V <sub>CC</sub> + 0.5	Output in HIGH or LOW State (Note 2)	V
I <sub>IK</sub>	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA
I <sub>OK</sub>	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA
		+50	V <sub>O</sub> > V <sub>CC</sub>	IIIA
lo	DC Output Source/Sink Current	±50		mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100		mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100		mA
T <sub>STG</sub>	Storage Temperature	-65 to +150		°C

# Recommended Operating Conditions (Note 3)

Symbol	Parameter			Max	Units	
V <sub>CC</sub>	Supply Voltage	2.0	3.6	V		
		Data Retention	1.5	3.6	v	
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage	HIGH or LOW State	0	V <sub>CC</sub>	V	
I <sub>OH</sub> /I <sub>OL</sub>	Output Current	$V_{CC} = 3.0V - 3.6V$		±24	mA	
		$V_{CC} = 3.0V - 3.6V$ $V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±12	IIIA	
		$V_{CC}=2.3V-2.7V$		±8		
T <sub>A</sub>	Free-Air Operating Temperature		-40	85	°C	
$\Delta t / \Delta V$	Input Edge Rate, V <sub>IN</sub> = 0.8V–2.0V, V <sub>CC</sub> = 3.0V		0	10	ns/V	

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I<sub>O</sub> Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

#### **DC Electrical Characteristics**

Symbol	Parameter	Conditions	V <sub>CC</sub>	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
		Conditions	(V)	Min	n Max	onito
VIH	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
V <sub>IL</sub>	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	v
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = -100 μA	2.3 - 3.6		0.2	
		I <sub>OL</sub> = 8 mA	2.3		0.6	
		I <sub>OL</sub> = 12 mA	2.7		0.4	v
		I <sub>OL</sub> = 16 mA	3.0		0.4	v
		I <sub>OL</sub> = 24 mA	3.0		0.55	
I	Input Leakage Current	$0 \le V_1 \le 5.5V$	2.3 - 3.6		±5.0	μA
I <sub>OFF</sub>	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		10	μA
		$3.6V \le V_I \le 5.5V$	2.3 - 3.6		±10	μΑ
۵l <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA

## **AC Electrical Characteristics**

Symbol	Parameter	$T_A = -40^{\circ}C$ to $+85^{\circ}C$ , $R_L = 500\Omega$						
		$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V <sub>CC</sub> = 2.7V C <sub>L</sub> = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		Units
t <sub>PZL</sub>	Propagation Delay Time	0.8	3.7	1.0	4.1	0.8	3.5	
t <sub>PLZ</sub>		0.8	3.7	1.0	4.1	0.8	3.5	ns

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>).

# **Dynamic Switching Characteristics**

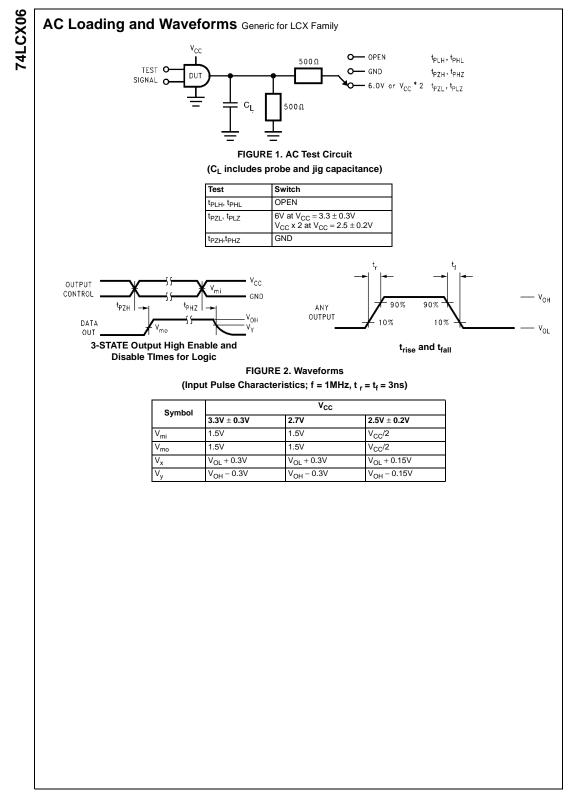
Symbol	Parameter	Conditions	V <sub>cc</sub>	$T_A = 25^{\circ}C$	Units
0,			(V)	Typical	
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.9	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	2.5	0.7	v
V <sub>OLV</sub>	Quiet Output Dynamic Valley V <sub>OL</sub>	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

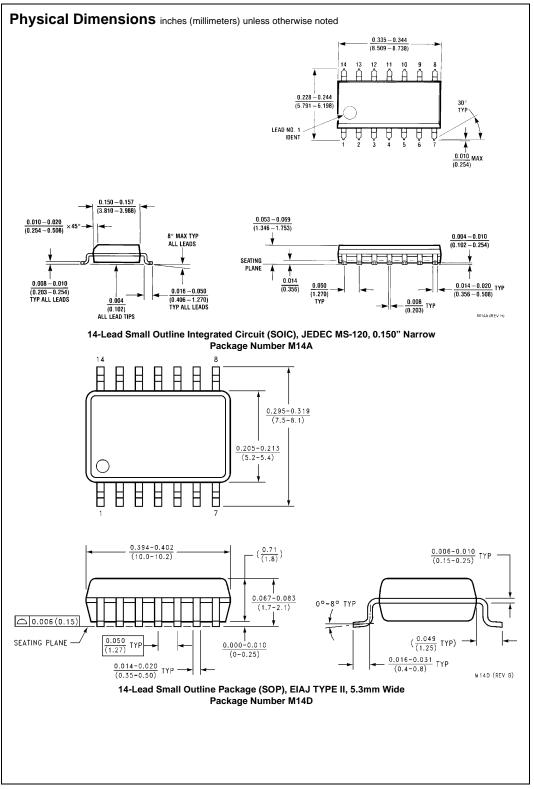
# Capacitance

Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$ , f = 10 MHz	25	pF

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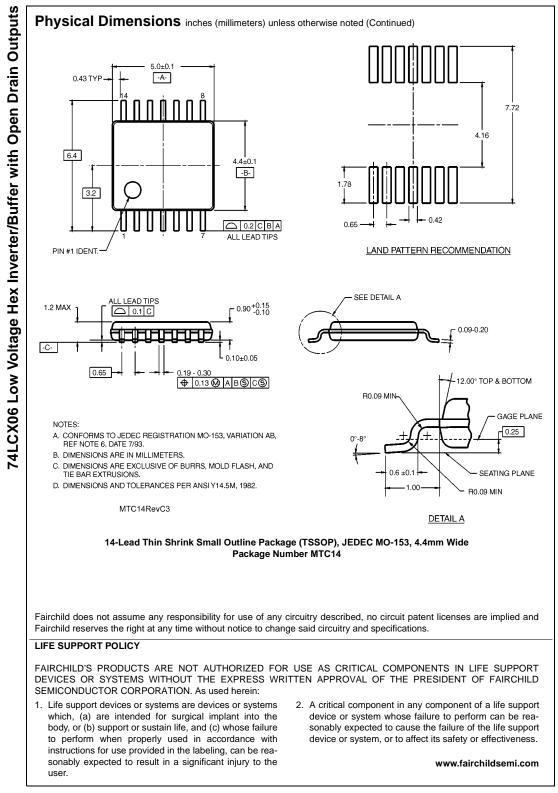
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